

February 2008

MM74HC125, MM74HC126 3-STATE Quad Buffers

Features

■ Typical propagation delay: 13ns
 ■ Wide operating voltage range: 2V–6V
 ■ Low input current: 1µA maximum

■ Low quiescent current: 80µA maximum (74HC)

■ Fanout of 15 LS-TTL loads

General Description

The MM74HC125 and MM74HC126 are general purpose 3-STATE high speed non-inverting buffers utilizing advanced silicon-gate CMOS technology. They have high drive current outputs which enable high speed operation even when driving large bus capacitances. These circuits possess the low power dissipation of CMOS circuitry, yet have speeds comparable to low power Schottky TTL circuits. Both circuits are capable of driving up to 15 low power Schottky inputs.

The MM74HC125 require the 3-STATE control input C to be taken high to put the output into the high impedance condition, whereas the MM74HC126 require the control input to be low to put the output into high impedance.

All inputs are protected from damage due to static discharge by diodes to V_{CC} and ground.

Ordering Information

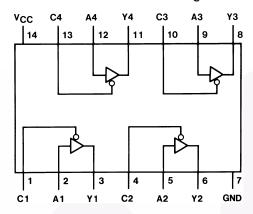
Order Number	Package Number	Package Description				
MM74HC125M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow				
MM74HC125SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide				
MM74HC125MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide				
MM74HC125N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide				
MM74HC126M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow				
MM74HC126SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide				
MM74HC126MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide				
MM74HC126N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide				

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.

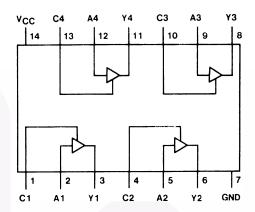
All packages are lead free per JEDEC: J-STD-020B standard.

Connection Diagrams

Pin Assignments for DIP, SOIC, SOP and TSSOP



Top View (MM74HC125)



Top View (MM74HC126)

Truth Tables

Inp	Output	
Α	С	Y
Н	L	Н
L	L	L
Х	Н	Z

MM74HC125

Inp	Inputs					
Α	С	Υ				
Н	Н	Н				
L	Н	L				
Х	L	Z				

MM74HC126

Absolute Maximum Ratings⁽¹⁾

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	-0.5 to +7.0V
V _{IN}	DC Input Voltage	–1.5 to V _{CC} +1.5V
V _{OUT}	DC Output Voltage	–0.5 to V _{CC} +0.5V
I _{IK} , I _{OK}	Clamp Diode Current	±20mA
I _{OUT}	DC Output Current, per pin	35mA
I _{CC}	DC V _{CC} or GND Current, per pin	±70mA
T _{STG}	Storage Temperature Range	−65°C to +150°C
P _D	Power Dissipation Note 2	600mW
	S.O. Package only	500mW
T _L	Lead Temperature (Soldering 10 seconds)	260°C

Notes:

- 1. Unless otherwise specified all voltages are referenced to ground.
- 2. Power Dissipation temperature derating plastic "N" package: -12mW/°C from 65°C to 85°C.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Units
V _{CC}	Supply Voltage	2	6	V
V _{IN} , V _{OUT}	DC Input or Output Voltage	0	V _{CC}	V
T _A	Operating Temperature Range	-40	+85	°C
t _r , t _f	Input Rise or Fall Times			
	$V_{CC} = 2.0V$		1000	ns
	V _{CC} = 4.5V		500	ns
	V _{CC} = 6.0V		400	ns

DC Electrical Characteristics⁽³⁾

				T _A =	25°C	T _A =-40°C to 85°C	T _A = -40°C to 125°C	
Symbol	Parameter	Conditions	V _{CC} (V)	Тур.		Guaranteed	Limits	Units
V _{IH}	Minimum HIGH		2.0		1.5	1.5	1.5	V
	Level Input Voltage		4.5		3.15	3.15	3.15	
	Voltage		6.0		4.2	4.2	4.2	
V _{IL}	Maximum LOW		2.0		0.5	0.5	0.5	V
	Level Input Voltage		4.5		1.35	1.35	1.35	
	Voltage		6.0		1.8	1.8	1.8	
V _{OH}	Minimum HIGH	$V_{IN} = V_{IH} \text{ or } V_{IL},$	2.0	2.0	1.9	1.9	1.9	V
	Level Output Voltage	I _{OUT} ≤ 20µA	4.5	4.5	4.4	4.4	4.4	
	voitage		6.0	6.0	5.9	5.9	5.9	
		$V_{IN} = V_{IH} \text{ or } V_{IL},$ $ I_{OUT} \le 6.0 \text{mA}$	4.5	4.2	3.98	3.84	3.7	
	3	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $ I_{OUT} \le 7.8 \text{mA}$	6.0	5.7	5.48	5.34	5.2	
V _{OL}	Level Output I _{OUT} ≤ 20µA	Maximum LOW $V_{IN} = V_{IH}$ or V_{IL} ,	2.0	0	0.1	0.1	0.1	V
		I _{OUT} ≤ 20μA	4.5	0	0.1	0.1	0.1	
	Voltage		6.0	0	0.1	0.1	0.1	
		$V_{IN} = V_{IH} \text{ or } V_{IL},$ $ I_{OUT} \le 6.0 \text{mA}$	4.5	0.2	0.26	0.33	0.4	
		$V_{IN} = V_{IH} \text{ or } V_{IL},$ $ I_{OUT} \le 7.8 \text{mA}$	6.0	0.2	0.26	0.33	0.4	
I _{OZ}	Maximum 3-STATE Output Leakage Current	$V_{IN} = V_{IH} \text{ or } V_{IL},$ $V_{OUT} = V_{CC} \text{ or GND,}$ $C_n = \text{Disabled}$	6.0		±0.5	±5	±10	μA
I _{IN}	Maximum Input Current	$V_{IN} = V_{CC}$ or GND	6.0		±0.1	±1.0	±1.0	μA
I _{CC}	Maximum Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0\mu A$	6.0		8.0	80	160	μA

Note:

3. For a power supply of 5V $\pm 10\%$ the worst case output voltages (V_{OH}, and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC}=5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN}, I_{CC}, and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

AC Electrical Characteristics

 $V_{CC} = 5V$, $T_A = 25^{\circ}C$, $C_L = 45pF$, $t_r = t_f = 6ns$

Symbol	Parameter	Conditions	Тур.	Guaranteed Limit	Units
t _{PHL} , t _{PLH}	Maximum Propagation Delay Time		13	18	ns
t _{PZH}	Maximum Output Enable Time to HIGH Level	$R_L = 1k\Omega$	13	25	ns
t _{PHZ}	Maximum Output Disable Time from HIGH Level	$R_L = 1k\Omega$, $C_L = 5pF$	17	25	ns
t _{PZL}	Maximum Output Enable Time to LOW Level	$R_L = 1k\Omega$	18	25	ns
t _{PLZ}	Maximum Output Disable Time from LOW Level	$R_L = 1k\Omega$, $C_L = 5pF$	13	25	ns

AC Electrical Characteristics

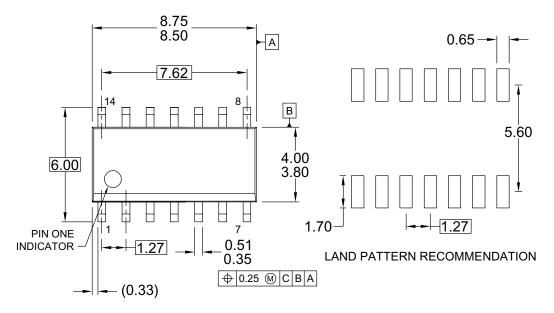
 V_{CC} = 2.0V to 6.0V, C_L = 50pF, t_r = t_f = 6ns (unless otherwise specified)

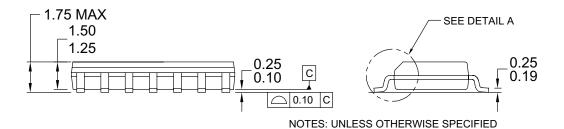
				T _A =	25°C	T _A = -40°C to 85°C	T _A = -40°C to 125°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Тур.		Guaranteed	Limits	Units
t _{PHL} , t _{PLH}	Maximum Propagation	2.0		40	100	125	150	ns
	Delay Time	4.5		14	20	25	30	
		6.0		12	17	21	25	
t _{PLH} , t _{PHL}	Maximum Propagation	2.0	C _L = 150pF	35	130	163	195	ns
	Delay Time	4.5		14	26	33	39	
		6.0		12	22	28	39	
t_{PZH}, t_{PZL}	Maximum Output	2.0	$R_L = 1k\Omega$	25	125	156	188	ns
	Enable Time			14	25	31	38	
		6.0		12	21	26	31	
t _{PHZ} , t _{PLZ}	Maximum Output	2.0	$R_L = 1k\Omega$	25	125	156	188	ns
	Disable Time	4.5		14	25	31	38	
		6.0		12	21	26	31	
t _{PZL} , t _{PZH}	Maximum Output	2.0	$C_L = 150 pF,$	35	140	175	210	ns
	Enable Time		$R_L = 1k\Omega$	15	28	35	42	
		6.0		13	24	30	36	
t _{TLH} , t _{THL}	Maximum Output	2.0V	$C_L = 50pF$	30	60	75	90	ns
	Rise and Fall Time	4.5V		7	12	15	18	
		6.0V		6	10	13	15	
C _{IN}	Input Capacitance			5	10	10	10	pF
C _{OUT}	Output Capacitance Outputs			15	20	20	20	pF
C _{PD}	Power Dissipation		Enabled	45				pF
	Capacitance (per gate) ⁽⁴⁾		Disabled	6				

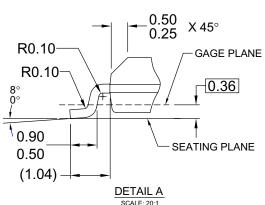
Note:

4. C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} \ V_{CC}^2 f + I_{CC} \ V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} \ V_{CC} \ f + I_{CC}$.

Physical Dimensions







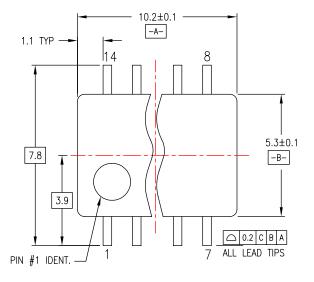
- A) THIS PACKAGE CONFORMS TO JEDEC MS-012, VARIATION AB, ISSUE C,
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS DO NOT INCLUDE MOLD FLASH OR BURRS.
- D) LANDPATTERN STANDARD: SOIC127P600X145-14M
- E) DRAWING CONFORMS TO ASME Y14.5M-1994
- F) DRAWING FILE NAME: M14AREV13

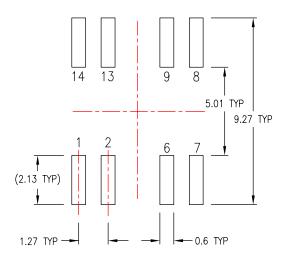
Figure 1. 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow

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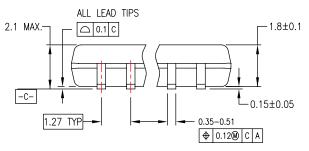
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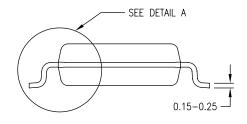
Physical Dimensions (Continued)





LAND PATTERN RECOMMENDATION

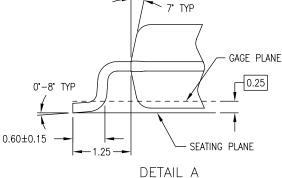




DIMENSIONS ARE IN MILLIMETERS

NOTES:

- A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.
 B. DIMENSIONS ARE IN MILLIMETERS.
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M14DREVC

Figure 2. 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide

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Physical Dimensions (Continued) 5.0±0.1 -A-0.65 0.43 TYP 6.4 4.4±0.1 -B-1.65 3.2 □ 0.2 C B A PIN #1 IDENT. 6.10 0.45LAND PATTERN RECOMMENDATION SEE DETAIL A ALL LEAD TIPS 0.90+0.15 1.2 MAX □ 0.1 C 0.09-0.20 -C-0.10±0.05 0.65 0.19 - 0.30⊕ |0.13\(\omega \ \omega \omega \ \omega \ \omega \ \omega \ \omega \omega \ \omeg 12.00°TOP & BOTTOM R0.09 min GAGE PLANE 0.25 0°-8° NOTES: 0.6±0.1 A. CONFORMS TO JEDEC REGISTRATION MO-153, SEATING PLANE R0.09min VARIATION AB, REF NOTE 6 -1 00 **B. DIMENSIONS ARE IN MILLIMETERS DETAIL A**

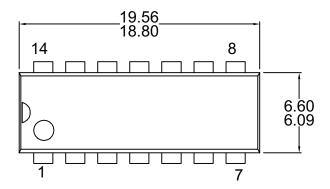
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS
- D. DIMENSIONING AND TOLERANCES PER ANSI Y14.5M, 1982
- E. LANDPATTERN STANDARD: SOP65P640X110-14M
- F. DRAWING FILE NAME: MTC14REV6

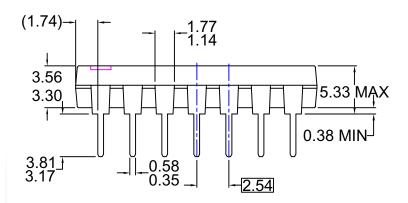
Figure 3. 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

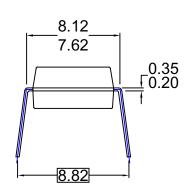
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Physical Dimensions (Continued)







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- B) ALL DIMENSIONS ARE IN MILLIMETERS.
 DIMENSIONS ARE EXCLUSIVE OF BURRS.
- C) MOLD FLASH, AND TIE BAR EXTRUSIONS.
- D) DIMENSIONS AND TOLERANCES PER ASME Y14.5-1994
- E) DRAWING FILE NAME: MKT-N14AREV7

Figure 4. 14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

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